



Product Overview

NTMFS4847N: Power MOSFET 30V 85A 4.1 mOhm Single N-Channel SO-8FL

For complete documentation, see the data sheet

Product Description

Power MOSFET 30 V, 85A, Single N-Channel,

FeaturesBenefits

- Low Capacitance
 - Low $R_{DS(on)}$
 - Optimized Gate Charge
 - Pb-Free
 - Thermally Enhanced SO-8 Package
- Minimize Driver Losses
 - Minimize Conduction Losses
 - Minimize Switching Losses
 - Environmentally Friendly

ApplicationsEnd Products

- CPU Power Delivery
 - DC-DC Converters
 - Refer to Application Note AND8195/D
- Notebook Computers
 - Servers/workstations

Part Electrical Specifications

Product	Compliance	Status	Channel Polarity	Configuration	$V_{DS(sat)}$ Min (V)	V_{GS} Max (V)	$V_{GS(th)}$ Max (V)	I_D Max (A)	P_D Max (W)	$r_{DS(on)}$ Max @ $V_{GS} = 2.5$ V (m)	$r_{DS(on)}$ Max @ $V_{GS} = 4.5$ V (m)	$r_{DS(on)}$ Max @ $V_{GS} = 10$ V (m)	Q_g Typ @ $V_{GS} = 4.5$ V (nC)	Q_g Typ @ $V_{GS} = 10$ V (nC)	Q_{gd} Typ @ $V_{GS} = 4.5$ V (nC)	Q_{rr} Typ (nC)	C_{iss} Typ (pF)	C_{oss} Typ (pF)	C_{rss} Typ (pF)	Package Type
NTMFS4847NAT3G	Pb-free Halide free	Active	N-Channel	Single	30	16	2.5	85	48.1		6.2	4.1	19.2		6.1	6	2614	466	241	SO-8FL / DF N-5

For more information please contact your local sales support at www.onsemi.com

Created on: 7/11/2015